2SA1530A

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE(Ultra super mini type)

DESCRIPTION

2SA1530A is a super mini package resin sealed silicon PNP epitaxial transistor,

It is designed for low frequency voltage application.

FEATURE

● Small collector to emitter saturation voltage.

VCE(sat)=-0.3Vmax(@Ic=-100mA, IB=-10mA)

- ●Excellent linearity of DC forward gain.
- Super mini package for easy mounting

APPLICATION

For Hybrid IC,small type machine low frequency voltage Amplify application.

MAXIMUM RATINGS(Ta=25°C)

Symbol	Parameter	Ratings	Unit
V _{CBO}	Collector to Base voltage	-60	٧
V _{CEO}	Collector to Emitter voltage	-50	٧
V _{EBO}	Emitter to Base voltage	-6	٧
I o	Collector current	-150	mA
P _c	Collector dissipation	200	mW
T _j	Junction temperature	+150	°C
T_{stg}	Storage temperature	-55 ~ +150	°C

JEITA: SC-59 TERMINAL CONNECTER ①: BASE ②: EMITTER ③: COLLECTOR

ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Comple al	Test conditions	Limits			Unit
Parameter	Symbol	Symbol Test conditions		Тур	Max	Unit
C to E break down voltage	V(BR)CEO	I _C = −100 μ A , R _{BE} = ∞	-50	-	-	٧
Collector cut off current	ICBO	$V_{CB} = -60V$, $I_{E} = 0mA$	-	-	-0.1	μΑ
Emitter cut off current	IEBO	V_{EB} = -4V , I $_{C}$ = 0mA	-	-	-0.1	μΑ
DC forward current gain	hFE	$V_{CE} = -6V$, $I_{C} = -1mA$	120	-	560	-
DC forward current gain	hFE	$V_{CE} = -6V$, $I_{C} = -0.1$ mA	70	-	_	-
C to E Saturation Vlotage	VCE(sat)	I_{C} = -100mA , I_{B} = -10mA	-	-	-0.3	٧
Gain bandwidth product	fT	V _{CE} = -6V , I _E = 10mA	-	200	-	MHz
Collector output capacitance	Cob	V_{CB} = -6 V , I_{E} = 0mA,f=1MHz	-	4	-	pF
Noise figure	NF	V_{CE} = -6V , I_{E} = 0.3mA,f=100Hz,RG=10k Ω	_	_	20	dB

 $\mbox{\em \%})$ It shows hFE classification in below table.

ltem	Q	R	S
h F E ltem	120~270	180~390	270~560

150

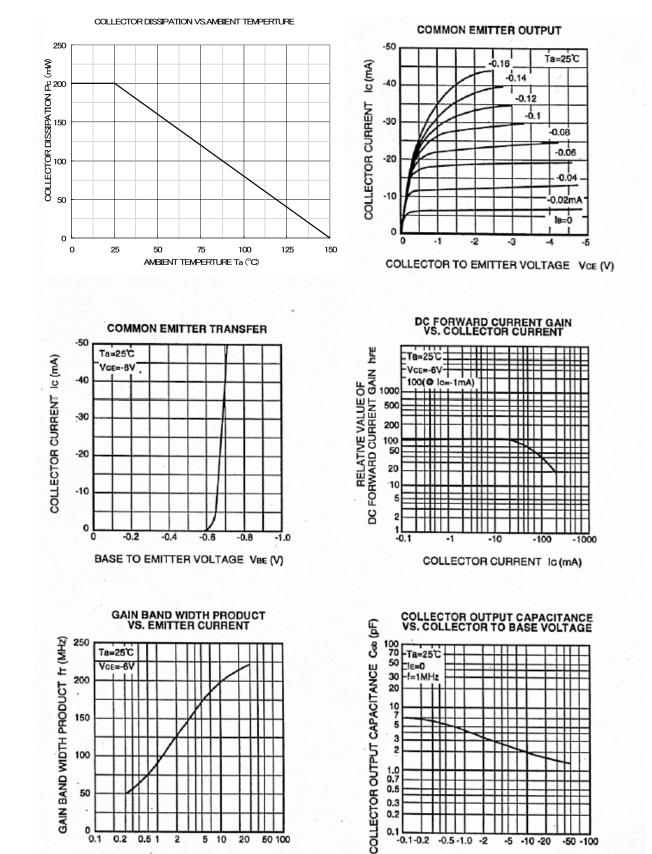
100

50

0.5 1

5 10 20 50 100

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE(Ultra super mini type)





10

0.5

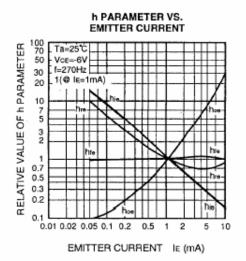
0.3

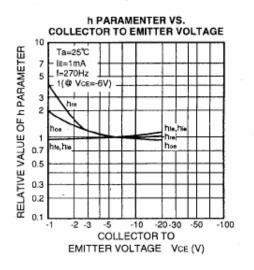
-0.1-0.2 -0.5 -1.0 -2

-5 -10 -20

-50 -100

FOR LOW FREQUENCY AMPLIFY APPLICATION SILICON PNP EPITAXIAL TYPE(Super mini type)





COMMON EMITTER h PARAMETER (TYPICAL VALUE)

Symbol	Parameter	Test conditions	Limits	Unit
hle	Closed loop small signal input impedance	Ta=25°C	7.0	kΩ
hre	Open loop small signal reverse voltage amplification factor	VCE=-6V	0.1	X10-3
hte	Closed loop small signal forward current amplification factor	IE=1mA	250	
hoe	Open loop, small signal output admittance	f=270Hz	18	μS



Marketing division, Marketing planning department 6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

Keep safety first in your circuit designs!

ISAHAYA Electronics Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage. Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (1) placement of substitutive, auxiliary, (2) use of non-farmable material or (3) prevention against any malfunction or mishap.

Notes regarding these materials

- These materials are intended as a reference to our customers in the selection of the ISAHAYA products best suited to the customer's application; they don't convey any license under any intellectual property rights, or any other rights, belonging
- ISAHAYA or third party.

 ISAHAYA or third party.

 ISAHAYA Electronics Corporation assumes no responsibility for any damage, or infringement of any third party's rights, originating in the use of any product data, diagrams, charts or circuit application examples contained in these materials.

 All information contained in these materials, including product data, diagrams and charts, represent information on products at the time of publication of these materials, and are subject to change by ISAHAYA Electronics Corporation without notice due to product improvements or other reasons. It is therefore recommended that customers contact ISAHAYA Electronics Corporation or an authorized ISAHAYA products distributor for the latest product information before purchasing product listed
- ISAHAYA Electronics Corporation products are not designed or manufactured for use in a device or system that is used under circumstances in which human life is potentially at stake. Please contact ISAHAYA electronics corporation or an authorized ISAHAYA products distributor when considering the use of a product contained herein for any specific purposes, such as apparatus or systems for transportation, vehicular, medical, aerospace, nuclear, or undersea repeater use.

 The prior written approval of ISAHAYA Electronics Corporation is necessary to reprint or reproduce in whole or in part these
- materials.
- If these products or technologies are subject to the Japanese export control restrictions, they must be exported under a license from the Japanese government and cannot be imported into a country other than the approved destination. Any diversion or re-export contrary to the export control laws and regulations of Japan and/or the country of destination is
- prohibited.

 Please contact ISAHAYA Electronics Corporation or authorized ISAHAYA products distributor for further details on these materials or the products contained therein.